DGG OR DGV PACKAGE

- Control Inputs VIH/VIL Levels are Referenced to V_{CCA} Voltage
- V_{CC} Isolation Feature If Either V_{CC} Input Is at GND, Both Ports Are in the **High-Impedance State**
- Overvoltage-Tolerant Inputs/Outputs Allow Mixed-Voltage-Mode Data Communications
- Fully Configurable Dual-Rail Design Allows Each Port to Operate Over the Full 1.65-V to 5.5-V Power-Supply Range
- Ioff Supports Partial-Power-Down Mode Operation

description/ordering information

This 16-bit noninverting bus transceiver uses two separate configurable power-supply rails. The A port is designed to track V_{CCA}. V_{CCA} accepts any supply voltage from 1.65 V to 5.5 V. The B port is designed to track V_{CCB}. V_{CCB} accepts any supply voltage from 1.65 V to 5.5 V. This allows for universal low-voltage bidirectional translation between any of the 1.8-V, 2.5-V, 3.3-V, and 5-V voltage nodes.

The SN74LVC16T245 is designed for asynchronous communication between data buses. The device transmits data from the A bus to the B bus or from the B bus to the A bus, depending on the logic level direction-control (DIR) input. The output-enable (OE) input can be used to disable the outputs so the buses are effectively isolated.

The SN74LVC16T245 is designed so that the control pins (1DIR, 2DIR, 1OE, and 2OE) are supplied by V_{CCA}.

RODUCT PREVIEW information concerns products in the formative or ign phase of development. Characteristic data and other cifications are design goals. Texas Instruments reserves the right to inge or discontinue these products without notice.

(TOP VIEW) 1DIR 48 10E 1B1 47 1 1A1 1B2 3 46 1A2 GND L 45 GND 44 🛮 1A3 1B3 L 1B4 43 | 1A4 6 42 V_{CCA} Vссв 1B5 8 41 1 1A5 40 L 1A6 1B6 L 9 39 GND GND 📙 10 1B7 🛚 11 38 | 1A7 1B8 L 12 37 1 1A8 2B1 13 36 2A1 2B2 35 2A2 14 15 GND L 34 GND 2B3 16 33 2A3 2B4 🛮 17 32 2A4 31 🛮 V_{CCA} 18 V_{CCB} 2B5 1119 30 2A5 2B6 🛮 20 29 2A6 28 GND GND L 21 27 2A7 2B7 🛮 22 2B8 🛮 23 26 2A8 2DIR 25 20E

ORDERING INFORMATION

TA	PACKA	AGE†	ORDERABLE PART NUMBER	TOP-SIDE MARKING
	TSSOP - DGG	Tape and reel	SN74LVC16T245DGGR	
-40°C to 85°C	TVSOP - DGV	Tape and reel	SN74LVC16T245DGVR	
100	VFBGA – GQL	Tape and reel	SN74LVC16T245GQLR	

Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of

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description/ordering information (continued)

This device is fully specified for partial-power-down applications using I_{off}. The I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

The V_{CC} isolation feature ensures that if either V_{CC} input is at GND, both ports are in the high-impedance state.

To ensure the high-impedance state during power up or power down, \overline{OE} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

GQL PACKAGE (TOP VIEW) 2 3 4 5 6 000000 000000 В 000000 С 000000 D \bigcirc \bigcirc 000000 G 000000 Н 000000 J 000000

terminal assignments

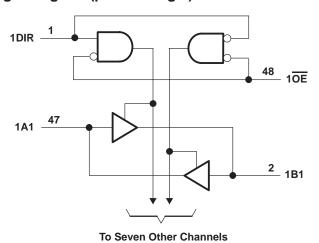
	1	2	3	4	5	6
Α	1DIR	NC	NC	NC	NC	1OE
В	1B2	1B1	GND	GND	1A1	1A2
С	1B4	1B3	VCCB	VCCA	1A3	1A4
D	1B6	1B5	GND	GND	1A5	1A6
Ε	1B8	1B7			1A7	1A8
F	2B1	2B2			2A2	2A1
G	2B3	2B4	GND	GND	2A4	2A3
Н	2B5	2B6	VCCB	VCCA	2A6	2A5
J	2B7	2B8	GND	GND	2A8	2A7
K	2DIR	NC	NC	NC	NC	2OE

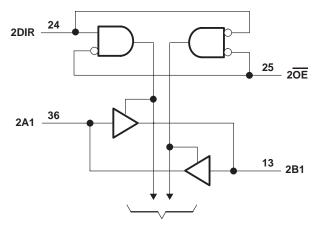
NC - No internal connection

FUNCTION TABLE (each 8-bit section)

INP	UTS	
ŌĒ	DIR	OPERATION
L	L	B data to A bus
L	Н	A data to B bus
Н	Χ	Isolation

logic diagram (positive logic)





To Seven Other Channels



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, , ,	,	–0.5 V to 6.5 V
	,	0.5 V to 6.5 V
Voltage range applied to any output in	the high-impedance	ce or power-off state, V _O
(see Note 1): (A port)		
(B port)		

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

 DGV package
 58°C/W

 GQL package
 42°C/W

 Storage temperature range, T_{stq}
 -65°C to 150°C

- NOTES: 1. The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.
 - 2. The output positive-voltage rating may be exceeded up to 6.5 V maximum if the output current rating is observed.
 - 3. The package thermal impedance is calculated in accordance with JESD 51-7.



[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

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recommended operating conditions (see Notes 4 through 6)

			VCCI	Vcco	MIN	MAX	UNIT
VCCA	0 1 1				1.65	5.5	.,
Vссв	Supply voltage				1.65	5.5	V
			1.65 V to 1.95 V		V _{CCI} × 0.65		
	High-level input	Data inputs	2.3 V to 2.7 V		1.7		
VIH	voltage	(see Note 7)	3 V to 3.6 V		2		V
			4.5 V to 5.5 V		V _{CCI} × 0.7		
			1.65 V to 1.95 V			V _{CCI} ×0.35	
	Low-level input	Data inputs	2.3 V to 2.7 V			0.7	.,
VIL	voltage	(see Note 7)	3 V to 3.6 V			0.8	V
			4.5 V to 5.5 V			V _{CCI} ×0.3	
			1.65 V to 1.95 V		V _{CCA} × 0.65		
	High-level input	DIR	2.3 V to 2.7 V		1.7		
VIH	voltage	(Referenced to V _{CCA}) (see Note 8)	3 V to 3.6 V		2		V
		(000110100)	4.5 V to 5.5 V		V _{CCA} ×0.7		
			1.65 V to 1.95 V			V _{CCA} × 0.35	
	Low-level input	DIR	2.3 V to 2.7 V			0.7	
V_{IL}	voltage	(Referenced to V _{CCA}) (see Note 8)	3 V to 3.6 V			0.8	V
		(000110100)	4.5 V to 5.5 V			V _{CCA} ×0.3	
٧ _I	Input voltage				0	5.5	V
.,	0	Active state			0	Vcco	.,
VO	Output voltage	3-State			0	3.6	V
				1.65 V to 1.95 V		-4	
	LPak laval autaut avas	-1		2.3 V to 2.7 V		-8	4
Іон	High-level output curre	nt		3 V to 3.6 V		-24	mA
				4.5 V to 5.5 V		-32	
				1.65 V to 1.95 V		4	
				2.3 V to 2.7 V		8	
lOL	Low-level output currer	nt		3 V to 3.6 V		24	mA
				4.5 V to 5.5 V		32	
			1.65 V to 1.95 V			20	
	Input transition rise or		2.3 V to 2.7 V			20	
Δt/Δv	fall rate Data inputs		3 V to 3.6 V			10	ns/V
		4.5 V to 5.5 V			5		
T _A	Operating free-air temp	l perature			-40	85	°C

NOTES: 4. $V_{\mbox{CCI}}$ is the $V_{\mbox{CC}}$ associated with the data input port.

- 5. VCCO is the VCC associated with the output port.
- All unused data inputs of the device must be held at V_{CCI} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.
- 7. For V_{CCI} values not specified in the data sheet, $V_{IH(min)} = V_{CCI} \times 0.7 \text{ V}$, $V_{IL(max)} = V_{CCI} \times 0.3 \text{ V}$.
- 8. For VCCI values not specified in the data sheet, VIH(min) = VCCA x 0.7 V, VIL(max) = VCCA x 0.3 V.



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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted) (see Notes 9 and 10)

			NT10110	.,	.,	T,	Δ = 25°C	;	–40°C t	o 85°C	
PARAN	METER	TEST COND	DITIONS	VCCA	VCCB	MIN	TYP	MAX	MIN	MAX	UNIT
		$I_{OH} = -100 \mu A$,	$V_I = V_{IH}$	1.65 V to 4.5 V	1.65 V to 4.5 V				V _{CCO} - 0.1	V	
		$I_{OH} = -4 \text{ mA},$	$V_I = V_{IH}$	1.65V	1.65 V				1.2		
Vон		$I_{OH} = -8 \text{ mA},$	VI = VIH	2.3 V	2.3 V				1.9		V
		$I_{OH} = -24 \text{ mA},$	$V_I = V_{IH}$	3 V	3 V				2.4		
		$I_{OH} = -32 \text{ mA},$	$V_I = V_{IH}$	4.5 V	4.5 V				3.8		
		$I_{OL} = 100 \mu A$,	$V_I = V_{IL}$	1.65 V to 4.5 V	1.65 V to 4.5 V					0.1	
		IOL = 4 mA,	$V_I = V_{IL}$	1.65 V	1.65 V					0.45	
V_{OL}		IOL = 8 mA,	VI = VIL	2.3 V	2.3 V					0.3	V
		I _{OL} = 24 mA,	VI = VIL	3 V	3 V					0.55	
		$I_{OL} = 32 \text{ mA},$	$V_I = V_{IL}$	4.5 V	4.5 V					0.55	
lį	DIR input	V _I = V _{CCA} or GN	ND	1.65 V to 5.5 V	1.65 V to 5.5 V			±1		±2	μΑ
	A or B	., ., ., .	- > /	0 V	0 to 5.5 V			±1		±2	
loff	port	V_I or $V_O = 0$ to 5	.5 V	0 to 5.5 V	0 V			±1		±2	μΑ
loz	A or B ports	VO = VCCO or GND	OE = V _{IH}	1.65 V to 5.5 V	1.65 V to 5.5 V			±1		±2	μΑ
	•			1.65 V to 5.5 V	1.65 V to 5.5 V					20	
ICCA		V _I = V _{CCI} or GND	$I_{O} = 0$	5 V	0 V					20	μΑ
		GIAD		0 V	5 V					-2	
				1.65 V to 5.5 V	1.65 V to 5.5 V					20	
ICCB		$V_I = V_{CCI}$ or GND	$I_{O} = 0$	5 V	0 V					-2	μΑ
		GIAD		0 V	5 V					20	
I _{CCA} +	ICCB	V _I = V _{CCI} or GND	I _O = 0	1.65 V to 5.5 V	1.65 V to 5.5 V					30	μΑ
	A port	One A port at V _C								50	
ΔICCA	DIR	DIR at V _{CCA} - 0 B port = OPEN, A port at V _{CCA} o		3 V to 5.5 V	3 V to 5.5 V					50	μА
ΔICCB	B port	One B port at V _C DIR at GND, A p		3 V to 5.5 V	3 V to 5.5 V					50	μΑ
Ci	DIR input	V _I = V _{CCA} or GN	ND	3.3 V	3.3 V						pF
C _{io}	A or B ports	VO = VCCA/B 0	r GND	3.3 V	3.3 V						pF

NOTES: 9. V_{CCO} is the V_{CC} associated with the output port.

10. V_{CCI} is the V_{CC} associated with the input port.



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switching characteristics over recommended operating free-air temperature range, V_{CCA} = 1.8 V \pm 0.15 V (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	TO	V _{CCB} = ± 0.1	= 1.8 V 5 V	V _{CCB} = ± 0.2	= 2.5 V 2 V	V _{CCB} =		V _{CCB}	= 5 V 5 V	UNIT
	(INPUT)	(OUTPUT)	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
^t PLH	А	В									ns
t _{PHL}	A	В									115
^t PLH	В	А									ns
t _{PHL}	Ь	^									115
^t PHZ	<u>o</u>	А									ns
^t PLZ	OE	A									115
^t PHZ	<u>OE</u>	В									20
^t PLZ	OE	В									ns
^t PZH	ŌĒ	А									ns
t _{PZL}	OE .	*									115
^t PZH	ŌĒ	В									ns
t _{PZL}	OE.	В									115

switching characteristics over recommended operating free-air temperature range, V_{CCA} = 2.5 V \pm 0.2 V (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	TO	V _{CCB} = ± 0.1	= 1.8 V 5 V	VCCB =	= 2.5 V 2 V	VCCB :	= 3.3 V 3 V	V _{CCB}	= 5 V 5 V	UNIT
	(INPUT)	(OUTPUT)	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
^t PLH	А	В									ns
t _{PHL}	A	Ь									115
^t PLH	В	А									ns
^t PHL	Ь	ζ.									115
^t PHZ	ŌĒ	А									ns
^t PLZ	OL	ζ									115
^t PHZ	<u>OE</u>	В									ns
t _{PLZ}	OE	Ь									115
^t PZH	ŌĒ	А									ns
t _{PZL}	OE .	A									115
^t PZH	ŌĒ	В									ns
t _{PZL}	OE .	В									115



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switching characteristics over recommended operating free-air temperature range, V_{CCA} = 3.3 V \pm 0.3 V (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	TO	V _{CCB} = ± 0.1	= 1.8 V 5 V	V _{CCB} =	= 2.5 V 2 V	V _{CCB} =		V _{CCB}	= 5 V 5 V	UNIT
	(INPUT)	(OUTPUT)	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
^t PLH	А	В									ns
^t PHL	A	В									115
^t PLH	В	А									ns
^t PHL	Ь	Λ									115
^t PHZ	<u>OE</u>	А									ns
^t PLZ	OE	A									115
^t PHZ	<u>OE</u>	В									ns
t _{PLZ}	OE	В									115
^t PZH	ŌĒ	А									ns
t _{PZL})E	A									110
^t PZH	ŌĒ	В									ns
t _{PZL}	OE.	В									115

switching characteristics over recommended operating free-air temperature range, V_{CCA} = 5 V \pm 0.5 V (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	TO	V _{CCB} = ± 0.1	= 1.8 V 5 V	V _{CCB} =		V _{CCB} =		V _{CCB}		UNIT
	(INPUT)	(OUTPUT)	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
^t PLH	Α	В									ns
^t PHL	٨	D									113
^t PLH	В	А									ns
t _{PHL}	Ь	Λ									115
^t PHZ	<u>OE</u>	А									ns
^t PLZ	OL	^									115
^t PHZ	ŌĒ	В									ns
^t PLZ	OL	D									115
t _{PZH} †	<u>OE</u>	А									20
t _{PZL} †	OE .	A									ns
t _{PZH} †	ŌĒ	В					·		·	·	ns
t _{PZL} †	OE .	В									115

operating characteristics, T_A = 25°C

	PARAMETER	TEST CONDITIONS	V _{CCA} = V _{CCB} = 1.8 V	V _{CCA} = V _{CCB} = 2.5 V	V _{CCA} = V _{CCB} = 3.3 V	V _{CCA} = V _{CCB} = 5 V	UNIT
Ct	A port input, B port output						
C _{pdA} †	B port input, A port output	C _L = 0, f = 10 MHz,					
C .st	A port input, B port output	$t_r = t_f = 1 \text{ ns}$					pF
C _{pdB} †	B port input, A port output]					

[†] Power-dissipation capacitance per transceiver



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power-up considerations

A proper power-up sequence always should be followed to avoid excessive supply current, bus contention, oscillations, or other anomalies. To guard against such power-up problems, take the following precautions:

- 1. Connect ground before any supply voltage is applied.
- 2. Power up V_{CCA}.
- 3. V_{CCB} can be ramped up along with or after V_{CCA} .

typical total static power consumption ($I_{CCA} + I_{CCB}$)

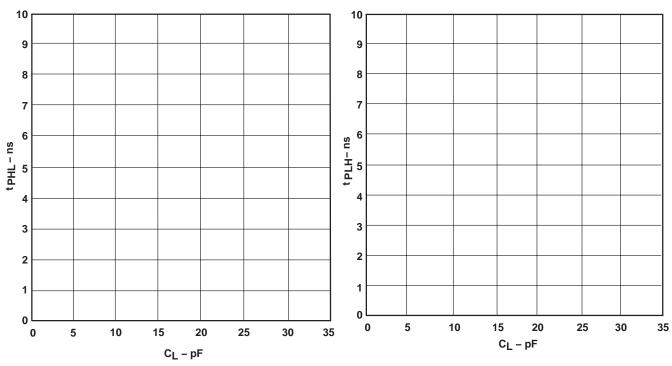
Table 1

.,,			VCCA			
VCCB	0 V	1.8 V	2.5 V	3.3 V	5 V	UNIT
0 V						
1.8 V						1
2.5 V						μΑ
3.3 V						
5 V						

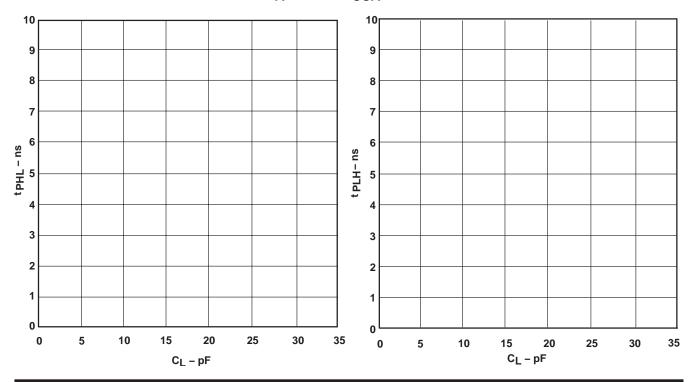
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TYPICAL CHARACTERISTICS

TYPICAL PROPAGATION DELAY (A TO B) vs LOAD CAPACITANCE $T_A = 25^{\circ}\text{C},\,V_{\text{CCA}} = 1.8\;\text{V}$



TYPICAL PROPAGATION DELAY (B TO A) vs LOAD CAPACITANCE $T_{A}=25^{\circ}\text{C},\,V_{CCA}=1.8\;\text{V}$

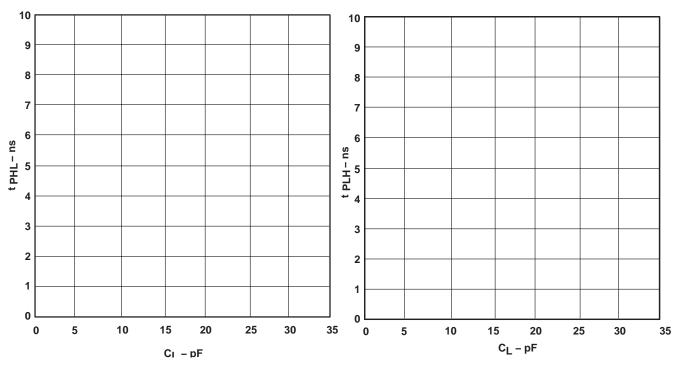




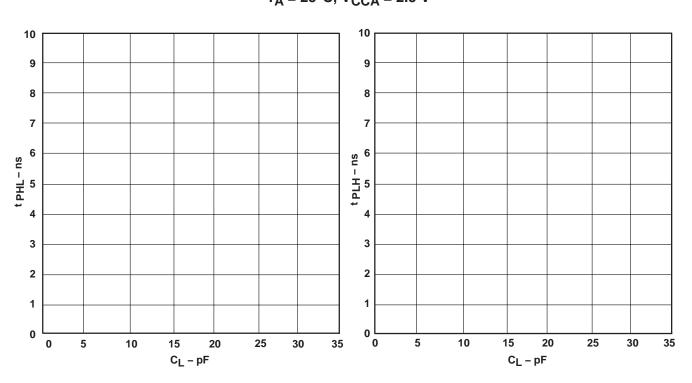
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TYPICAL CHARACTERISTICS

TYPICAL PROPAGATION DELAY (A TO B) vs LOAD CAPACITANCE $\rm T_A = 25^{\circ}C, \, \rm V_{CCA} = 2.5 \, \rm V$



TYPICAL PROPAGATION DELAY (B TO A) vs LOAD CAPACITANCE $T_{A}=25^{\circ}\text{C},\,V_{CCA}=2.5\,\text{V}$

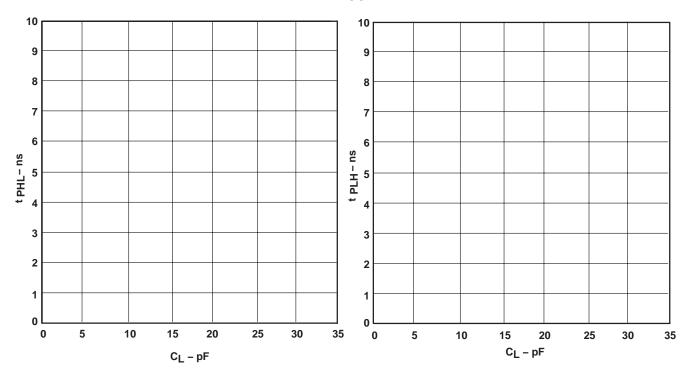




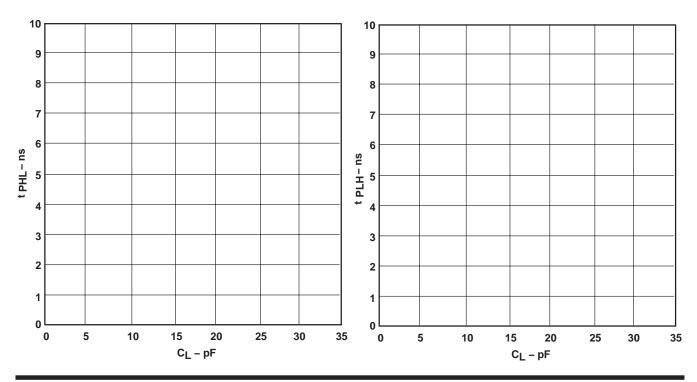
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TYPICAL CHARACTERISTICS

TYPICAL PROPAGATION DELAY (A TO B) vs LOAD CAPACITANCE $T_{A}=25^{\circ}\text{C},\,V_{\text{CCA}}=3.3\;\text{V}$



TYPICAL PROPAGATION DELAY (B TO A) vs LOAD CAPACITANCE $T_{A}=25^{\circ}\text{C},\,V_{\text{CCA}}=3.3\;\text{V}$

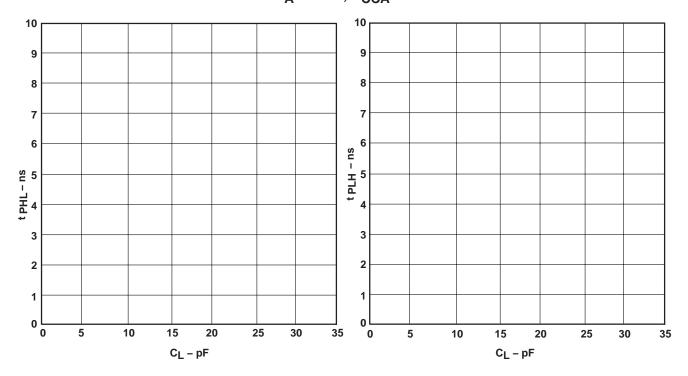




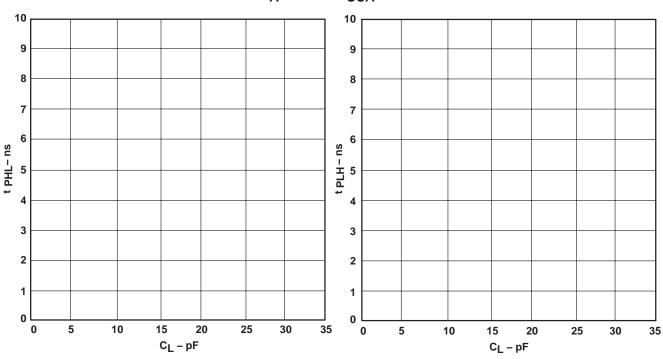
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TYPICAL CHARACTERISTICS

TYPICAL PROPAGATION DELAY (A to B) vs LOAD CAPACITANCE T_{A} = 25°C, V_{CCA} = 5 V



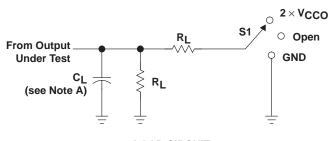
TYPICAL PROPAGATION DELAY (B TO A) vs LOAD CAPACITANCE T_{A} = 25°C, V_{CCA} = 5 V





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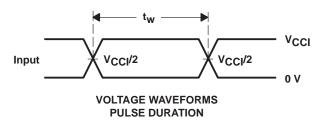
PARAMETER MEASUREMENT INFORMATION

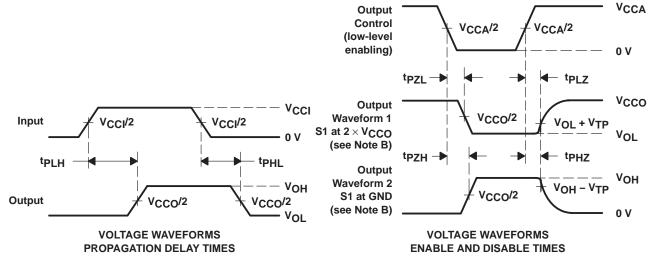


TEST	S1
tpd	Open
tPLZ/tPZL	2×V _{CCO}
tPHZ/tPZH	GND

LOAD CIRCUIT

Vcco	CL	RL	VTP
1.8 V \pm 0.15 V	15 pF	2 k Ω	0.15 V
2.5 V \pm 0.2 V	15 pF	2 k Ω	0.15 V
3.3 V \pm 0.3 V	15 pF	2 k Ω	0.3 V
5 V \pm 0.5 V	15 pF	2 k Ω	0.3 V





NOTES: A. C_I includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_O = 50 Ω , dv/dt \geq 1 V/ns, dv/dt \geq 1 V/ns.
- D. The outputs are measured one at a time, with one transition per measurement.
- E. tpLz and tpHz are the same as tdis.
- F. tpzL and tpzH are the same as ten.
- G. tpLH and tpHL are the same as tpd.
- H. V_{CCI} is the V_{CC} associated with the input port.
- I. V_{CCO} is the V_{CC} associated with the output port.
- J. All parameters and waveforms are not applicable to all devices.

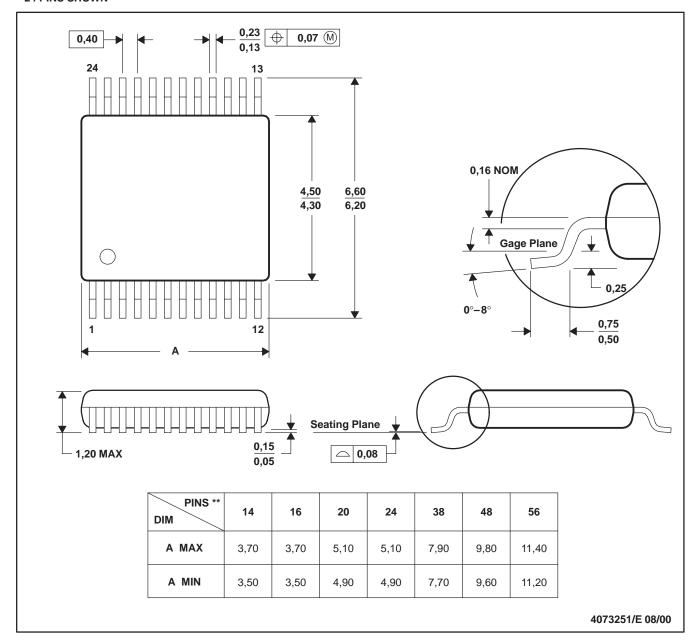
Figure 2. Load Circuit and Voltage Waveforms



DGV (R-PDSO-G**)

24 PINS SHOWN

PLASTIC SMALL-OUTLINE



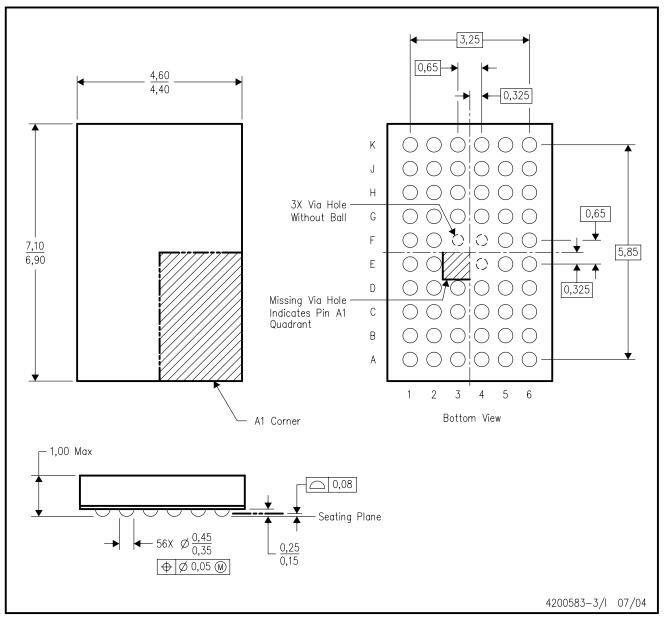
NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15 per side.
- D. Falls within JEDEC: 24/48 Pins MO-153 14/16/20/56 Pins – MO-194



GQL (R-PBGA-N56)

PLASTIC BALL GRID ARRAY



NOTES:

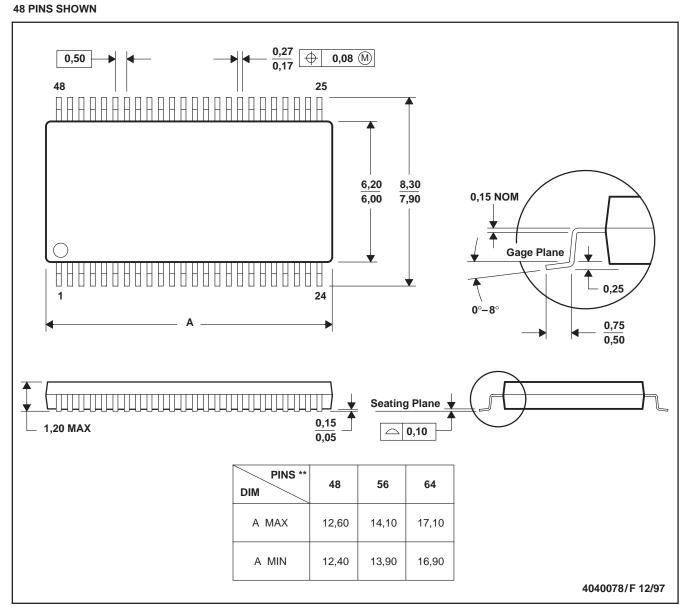
- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Falls within JEDEC MO-225 variation BA.
- D. This package is tin-lead (SnPb). Refer to the 56 ZQL package (drawing 4204437) for lead-free.



DGG (R-PDSO-G**)

......

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold protrusion not to exceed 0,15.
- D. Falls within JEDEC MO-153



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